## NSN 5961-01-072-1454

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Inclosure Material:

Metal

**Overall Length:** 

Between 0.325 inches and 0.460 inches

**Mounting Facility Quantity:** 

1

**Internal Configuration:** 

Junction contact

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-61

**Mounting Method:** 

Threaded stud

**Features Provided:** 

Hermetically sealed case

**Overall Width Across Flats:** 

Between 0.667 inches and 0.687 inches

**Thread Size:** 

0.250 inches

**Semiconductor Material:** 

Silicon

Voltage Rating In Volts Per Characteristic:

120.0 collector to base voltage/static/emitter open and 100.0 collector to emitter voltage/static/base open and 6.0 emitter to base voltage, static, collector open

**Current Rating Per Characteristic:** 

25.00 amperes source cutoff current and 10.00 amperes source cutoff current

Power Rating Per Characteristic:

100.0 watts small-signal input power, common-collector preset

**Maximum Operating Tempurature Per Measurement Point:** 

200.0 degrees celsius ambient air

**Special Features:** 

voltage; junction pattern arrangement: npn

**Precious Material And Location:** 

Terminal surfaces gold

**Precious Material:** 

Gold

**Test Data Document:** 

82577-928765 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

**Thread Series Designator:** 

Unf

**Terminal Type And Quantity:** 

3 tab, solder lug

Shelf Life:

N/a

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Demilitarization:

No

Fiig:

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